

157

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Title:Terahertz direct detection in YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> microbolometers

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Abstract:A high sensitivity broadband terahertz direct detector based on YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> high-T<sub>c</sub> superconductor microbolometers is presented. At 77 K, the responsivity of the spiral antenna-integrated microbolometers (1.5 μm × 1.5 μm) is 190 V/W, referenced to the input of the silicon substrate lens, across the frequency range of 330 GHz-1.63 THz in a single device. The response time is approximately 300 ps. Using a room temperature readout, we measure an optical noise equivalent power (NEP) of 20 pW/Hz<sup>0.5</sup> (readout noise limited) for modulation frequencies ranging from 500 Hz to 100 kHz.

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